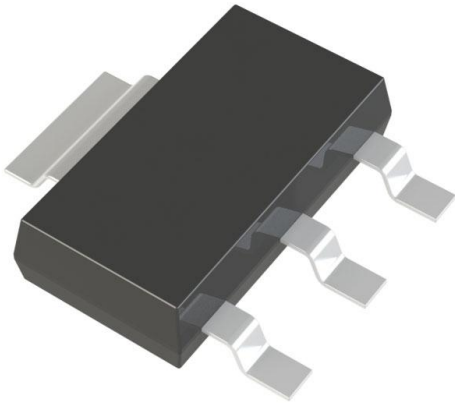


# DPLS350E-13 Datasheet

[www.digi-electronics.com](http://www.digi-electronics.com)



<https://www.DiGi-Electronics.com>

DiGi Electronics Part Number	DPLS350E-13-DG
Manufacturer	<a href="#">Diodes Incorporated</a>
Manufacturer Product Number	DPLS350E-13
Description	TRANS PNP 50V 3A SOT223-3
Detailed Description	Bipolar (BJT) Transistor PNP 50 V 3 A 100MHz 1 W S urface Mount SOT-223-3



Tel: +00 852-30501935

RFQ Email: [Info@DiGi-Electronics.com](mailto:Info@DiGi-Electronics.com)

DiGi is a global authorized distributor of electronic components.

## Purchase and inquiry

Manufacturer Product Number:

DPLS350E-13

Series:

-

Transistor Type:

PNP

Voltage - Collector Emitter Breakdown (Max):

50 V

Current - Collector Cutoff (Max):

100nA (ICBO)

Power - Max:

1 W

Operating Temperature:

-55°C ~ 150°C (TJ)

Package / Case:

TO-261-4, TO-261AA

Base Product Number:

DPLS350

Manufacturer:

Diodes Incorporated

Product Status:

Active

Current - Collector (Ic) (Max):

3 A

Vce Saturation (Max) @ Ib, Ic:

300mV @ 200mA, 2A

DC Current Gain (hFE) (Min) @ Ic, Vce:

100 @ 2A, 2V

Frequency - Transition:

100MHz

Mounting Type:

Surface Mount

Supplier Device Package:

SOT-223-3

## Environmental & Export classification

RoHS Status:

ROHS3 Compliant

REACH Status:

REACH Unaffected

HTSUS:

8541.29.0075

Moisture Sensitivity Level (MSL):

1 (Unlimited)

ECCN:

EAR99

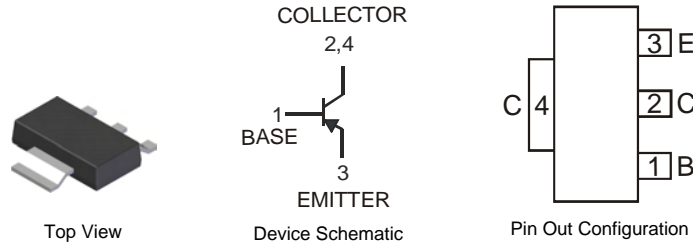
**DPLS350E****LOW  $V_{CE(SAT)}$  PNP SURFACE MOUNT TRANSISTOR**

## Features

- Epitaxial Planar Die Construction
- Ideally Suited for Automated Assembly Processes
- Ideal for Medium Power Switching or Amplification Applications
- **Lead Free By Design/RoHS Compliant (Note 1)**
- **"Green" Device (Note 2)**

## Mechanical Data

- Case: SOT-223
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals: Finish — Matte Tin annealed over Copper leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208
- Marking Information: See Page 4
- Ordering Information: See Page 4
- Weight: 0.115 grams (approximate)



## Maximum Ratings @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	-60	V
Collector-Emitter Voltage	$V_{CEO}$	-50	V
Emitter-Base Voltage	$V_{EBO}$	-6	V
Peak Pulse Current	$I_{CM}$	-5	A
Continuous Collector Current	$I_C$	-3	A
Base Current	$I_B$	-1	A

## Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 3) @ $T_A = 25^\circ\text{C}$	$P_D$	1	W
Thermal Resistance, Junction to Ambient Air (Note 3) @ $T_A = 25^\circ\text{C}$	$R_{\theta JA}$	125	$^\circ\text{C/W}$
Operating and Storage Temperature Range	$T_J, T_{STG}$	-55 to +150	$^\circ\text{C}$

- Notes:
1. No purposefully added lead.
  2. Diodes Inc.'s "Green" policy can be found on our website at [http://www.diodes.com/products/lead\\_free/index.php](http://www.diodes.com/products/lead_free/index.php).
  3. Device mounted on FR-4 PCB; pad layout as shown on page 4 or in Diodes Inc. suggested pad layout document AP02001, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.



## Electrical Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Conditions
<b>OFF CHARACTERISTICS (Note 4)</b>						
Collector-Base Cutoff Current	$I_{CBO}$	—	—	-100	nA	$V_{CB} = -50\text{V}, I_E = 0$
Emitter-Base Cutoff Current	$I_{EBO}$	—	—	-50	$\mu\text{A}$	$V_{CB} = -50\text{V}, I_E = 0, T_A = 150^\circ\text{C}$
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	-50	—	—	V	$V_{EB} = -5\text{V}, I_C = 0$
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	-50	—	—	V	$I_C = -10\text{mA}$
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	-5	—	—	V	$I_E = -100\mu\text{A}$
<b>ON CHARACTERISTICS (Note 4)</b>						
DC Current Gain	$h_{FE}$	200	—	—	—	$V_{CE} = -2\text{V}, I_C = -0.5\text{A}$
		200	—	—		$V_{CE} = -2\text{V}, I_C = -1\text{A}$
		100	—	—		$V_{CE} = -2\text{V}, I_C = -2\text{A}$
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$	—	—	-100	mV	$I_C = -0.5\text{A}, I_B = -50\text{mA}$
		—	—	-180		$I_C = -1\text{A}, I_B = -50\text{mA}$
		—	—	-300		$I_C = -2\text{A}, I_B = -200\text{mA}$
Equivalent On-Resistance	$R_{CE(SAT)}$	—	67	150	$\text{m}\Omega$	$I_E = -2\text{A}, I_B = -200\text{mA}$
Base-Emitter Saturation Voltage	$V_{BE(SAT)}$	—	—	-1.2	V	$I_C = -2\text{A}, I_B = -200\text{mA}$
Base-Emitter Turn-on Voltage	$V_{BE(ON)}$	—	—	-1.1	V	$V_{CE} = -2\text{V}, I_C = -1\text{A}$
<b>SMALL SIGNAL CHARACTERISTICS</b>						
Transition Frequency	$f_T$	100	—	—	MHz	$V_{CE} = -5\text{V}, I_C = -100\text{mA}, f = 100\text{MHz}$
Output Capacitance	$C_{obo}$	—	—	40	pF	$V_{CB} = -10\text{V}, f = 1\text{MHz}$

Notes: 4. Measured under pulsed conditions. Pulse width = 300 $\mu\text{s}$ . Duty cycle  $\leq 2\%$ .

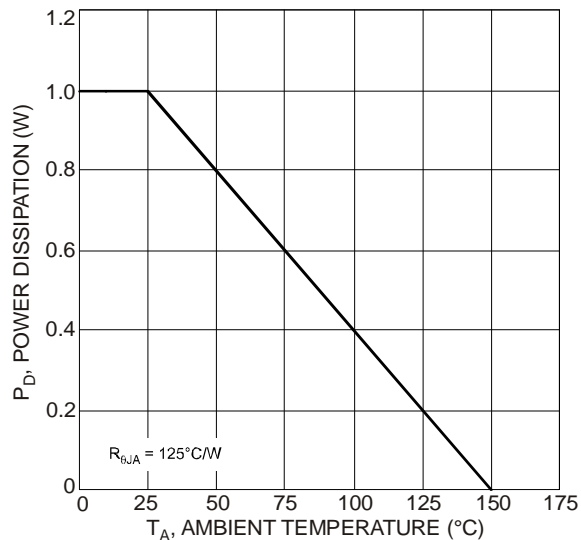


Fig. 1 Power Dissipation vs. Ambient Temperature (Note 3)

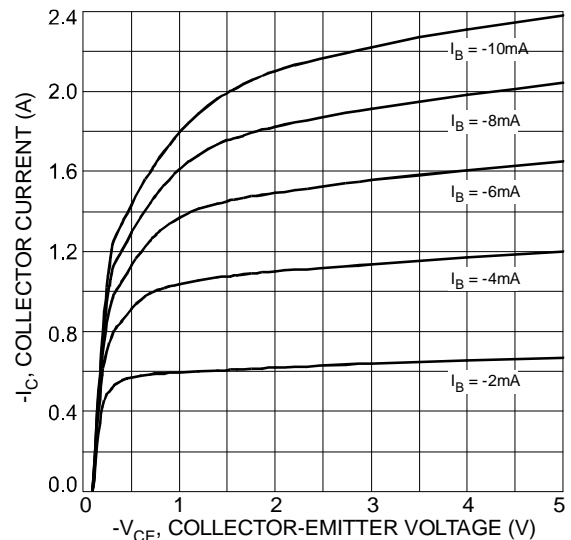


Fig. 2 Typical Collector Current vs. Collector-Emitter Voltage



**DPLS350E**

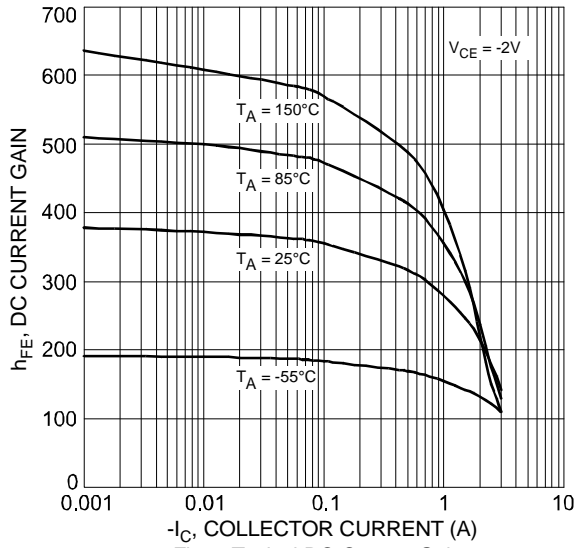


Fig. 3 Typical DC Current Gain vs. Collector Current

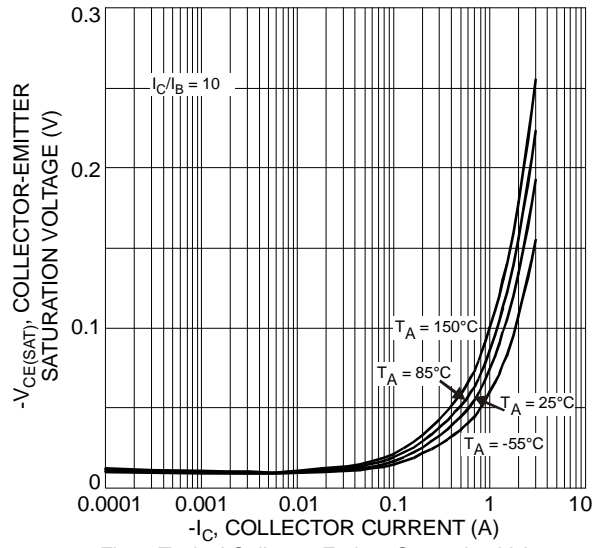


Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current

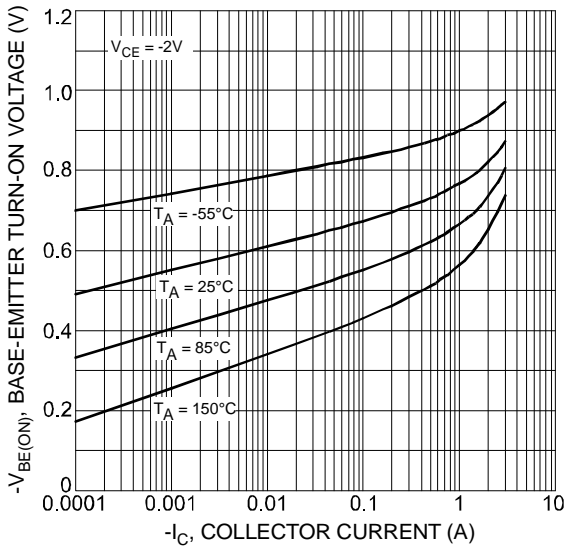


Fig. 5 Typical Base-Emitter Turn-On Voltage vs. Collector Current

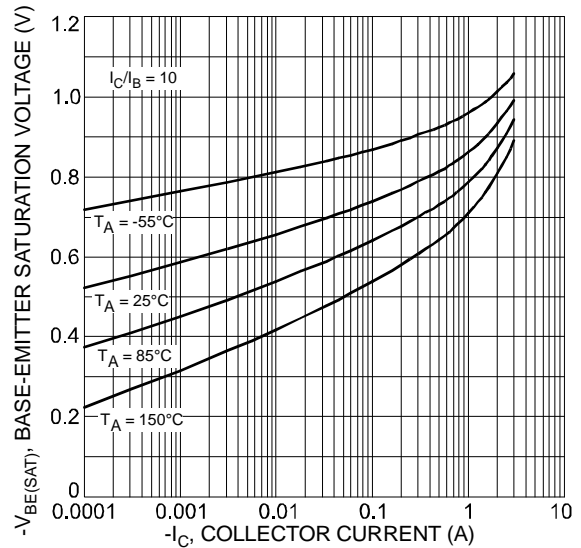


Fig. 6 Typical Base-Emitter Saturation Voltage vs. Collector Current

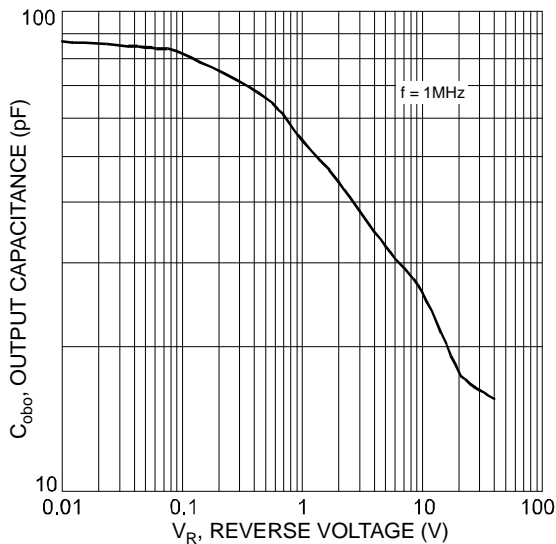


Fig. 7 Typical Output Capacitance Characteristics

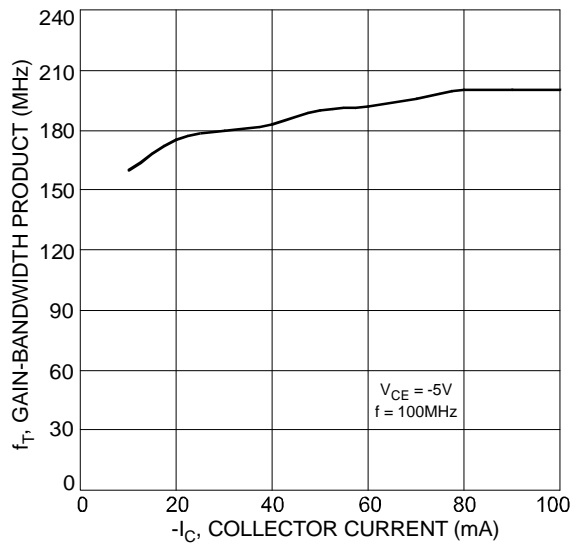


Fig. 8 Typical Gain-Bandwidth Product vs. Collector Current



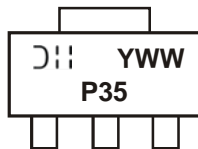
DPLS350E

## Ordering Information (Note 5)

Part Number	Case	Packaging
DPLS350E-13	SOT-223	2500/Tape & Reel

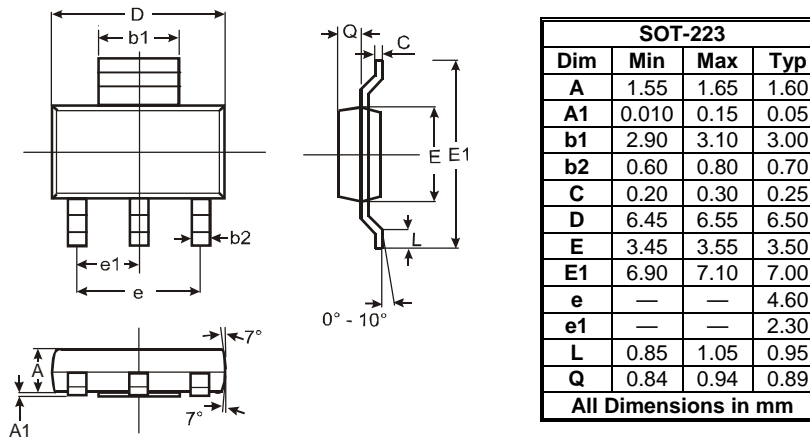
Notes: 5. For packaging details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

## Marking Information

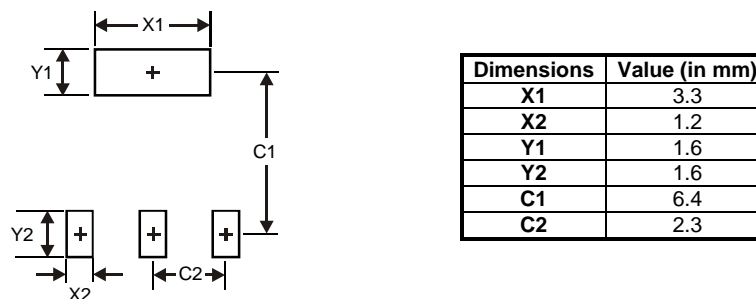


P35 = Product Type Marking Code  
 DIP = Manufacturer's Code Marking  
 YWW = Date Code Marking  
 Y = Last digit of year (ex: 7 = 2007)  
 WW = Week code 01 - 52

## Package Outline Dimensions



## Suggested Pad Layout



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